

# LMG310xR0xx 100V GaN Power Stage With Integrated Protection and Smart-Switching Features

## 1 Features

- 100V GaN power stage with integrated driver: (GaN FET  $R_{DS(ON)}$  options: 1.1m $\Omega$  and 1.7m $\Omega$ )
- Integrated high-side level shift and bootstrap
  - Two LMG310xR0xx can form a half-bridge
  - No external level shifter is required
- Efficient and high-density power conversion with
  - Ultra-low propagation delay (20ns) and matching (7ns)
  - Independent turn-on and turn-off slew-rate control for the GaN FET
  - Zero-voltage detection (ZVD) reporting for dead-time optimization
  - Ideal diode mode turn-on (IDM) and turn-off (zero current detection ZCD) to reduce third quadrant losses in soft switching application
- Input control flexibility
  - Independent input mode (IIM) control
  - Single PWM input with resistor programmable dead time option for IO-limited controllers
- Robust protection
  - Interlock protection in IIM (LMG3104R0xx)
  - Internal bootstrap supply voltage regulation to prevent GaN FET overdrive
  - $V_{DS}$  monitoring based cycle-by-cycle short-circuit protection
  - Fault indication for overtemperature, supply undervoltage, and short-circuit events
- External bias power supply: 5V
  - Supports 3.3V and 5V input logic levels
- Parasitic optimized QFN package with exposed top pad to support top-side cooling

## 2 Applications

- Buck, boost, and buck-boost converters
- LLC converters
- [Solar inverters](#)
- [Telecom and server power](#)
- [Motor drives](#)
- [Power tools](#)
- [Class-D audio amplifiers](#)

## 3 Description

The LMG310xR0xx devices are a family of 100V enhancement-mode Gallium Nitride (GaN) HEMT with integrated high frequency driver. The LMG310xR0xx incorporates a high side level shifter and bootstrap circuit, so that two LMG310xR0xx devices can be used to form a half bridge without an additional level shifter. LMG3104R0xx offers logic input interlock in Independent Input Mode (IIM).

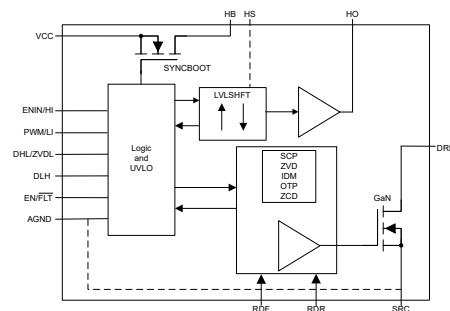
GaN FETs provide significant advantages for power conversion as GaN FETs have zero reverse recovery, very small input capacitance  $C_{ISS}$ , and output capacitance  $C_{OSS}$ . The driver and the GaN FET are mounted on a completely bond-wire free package platform with minimized package parasitic elements. The LMG310xR0xx device is available in a 6.5mm × 4mm lead-free package and can be easily mounted on PCBs.

The TTL logic compatible inputs support 3.3V and 5V logic levels, regardless of the VCC voltage. A proprietary bootstrap voltage control technique regulates the gate voltages of the enhancement mode GaN FETs within the safe operating range. The device extends advantages of discrete GaN FETs by offering a more user-friendly interface. The device is an excellent option for applications requiring high-frequency, high-efficiency operation in a small form factor.

### Device Information

PART NUMBER <sup>(3)</sup>	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>
LMG310xR011	VBE (VQFN-FCRLF, 15)	6.5mm × 4mm
LMG310xR017		

- (1) For more information, see [Section 7](#).
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.
- (3) See the [Device Comparison Tables](#).



**Simplified Block Diagram**



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## 4 Device Comparison

**Table 4-1. Device Comparison**

DEVICE		RDS <sub>(ON)</sub> (mΩ)
LMG3105R011VBER	LMG3104R011VBER	1.1
LMG3105R017VBER <sup>(1)</sup>	LMG3104R017VBER	1.7

(1) Preview information (not Advance Information)

**Table 4-2. Feature Comparison**

PART NUMBER	INTERLOCK IN IIM MODE	IDM IN TURN-OFF TRANSITION
LMG3104Rxxx	Enabled	Enabled
LMG3105Rxxx	Disabled	Disabled

## 5 Device and Documentation Support

### 5.1 Documentation Support

#### 5.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Layout Considerations for LMG5200 GaN Power Stage application note](#)
- Texas Instruments, [Using the LMG5200: GaN Half-Bridge Power Stage EVM user's guide](#)
- Texas Instruments, [AN-2029 Handling and Process Recommendations application note](#)

### 5.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 5.3 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 5.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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### 5.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 5.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

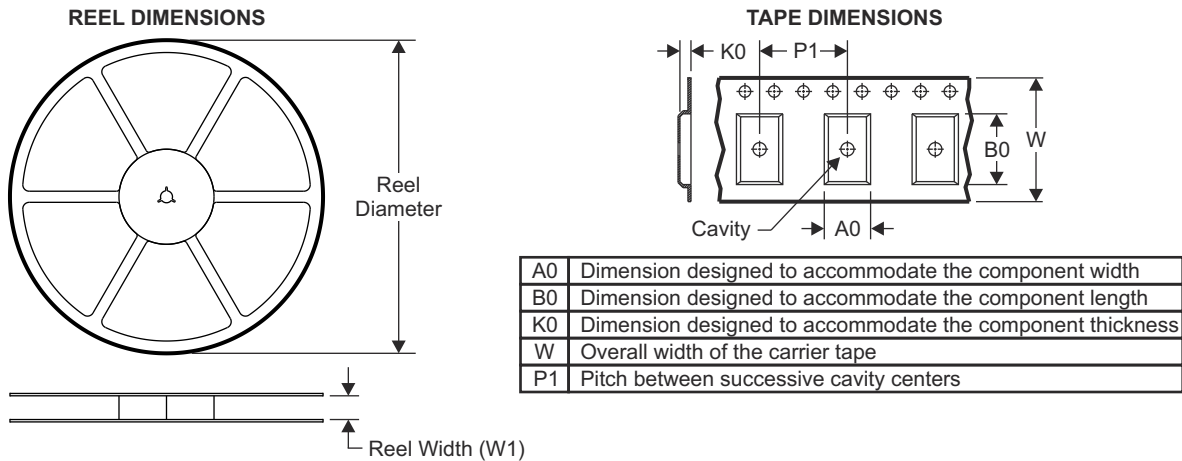
## 6 Revision History

DATE	REVISION	NOTES
May 2026	*	Initial Release

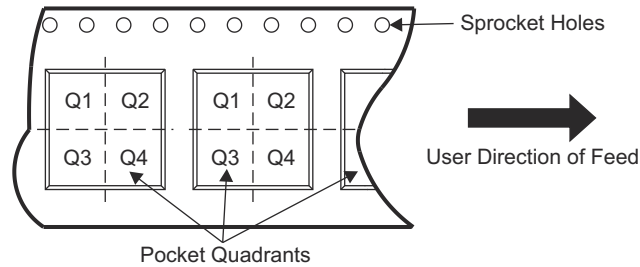
## 7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

### 7.1 Tape and Reel Information

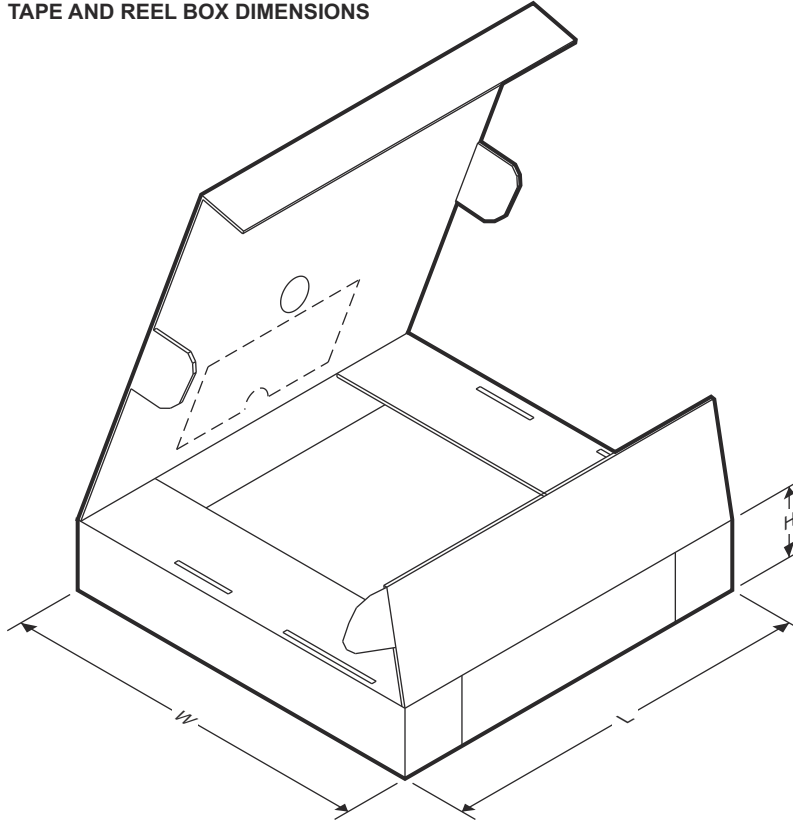


#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMG3104R011VBER	VQFN-FCRLF	VBE	15	2000	330	16.4	4.3	6.8	1.1	8.0	16.0	Q1
LMG3104R017VBER	VQFN-FCRLF	VBE	15	2000	330	16.4	4.3	6.8	1.1	8.0	16.0	Q1
LMG3105R011VBER	VQFN-FCRLF	VBE	15	2000	330	16.4	4.3	6.8	1.1	8.0	16.0	Q1
LMG3105R017VBER (Preview)	VQFN-FCRLF	VBE	15	2000	330	16.4	4.3	6.8	1.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

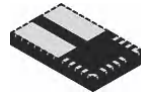


ADVANCE INFORMATION

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMG3104R011VBER	VQFN-FCRLF	VBE	15	2000	336.6	336.6	28.6
LMG3104R017VBER	VQFN-FCRLF	VBE	15	2000	336.6	336.6	28.6
LMG3105R011VBER	VQFN-FCRLF	VBE	15	2000	336.6	336.6	28.6
LMG3105R017VBER (Preview)	VQFN-FCRLF	VBE	15	2000	336.6	336.6	28.6

**7.2 Mechanical Data**

The LMG310xR0xx device package is rated as an MSL3 package (Moisture Sensitivity Level 3). Refer to [AN-2029 Handling and Process Recommendations application note](#) for specific handling and process recommendations of an MSL3 package.

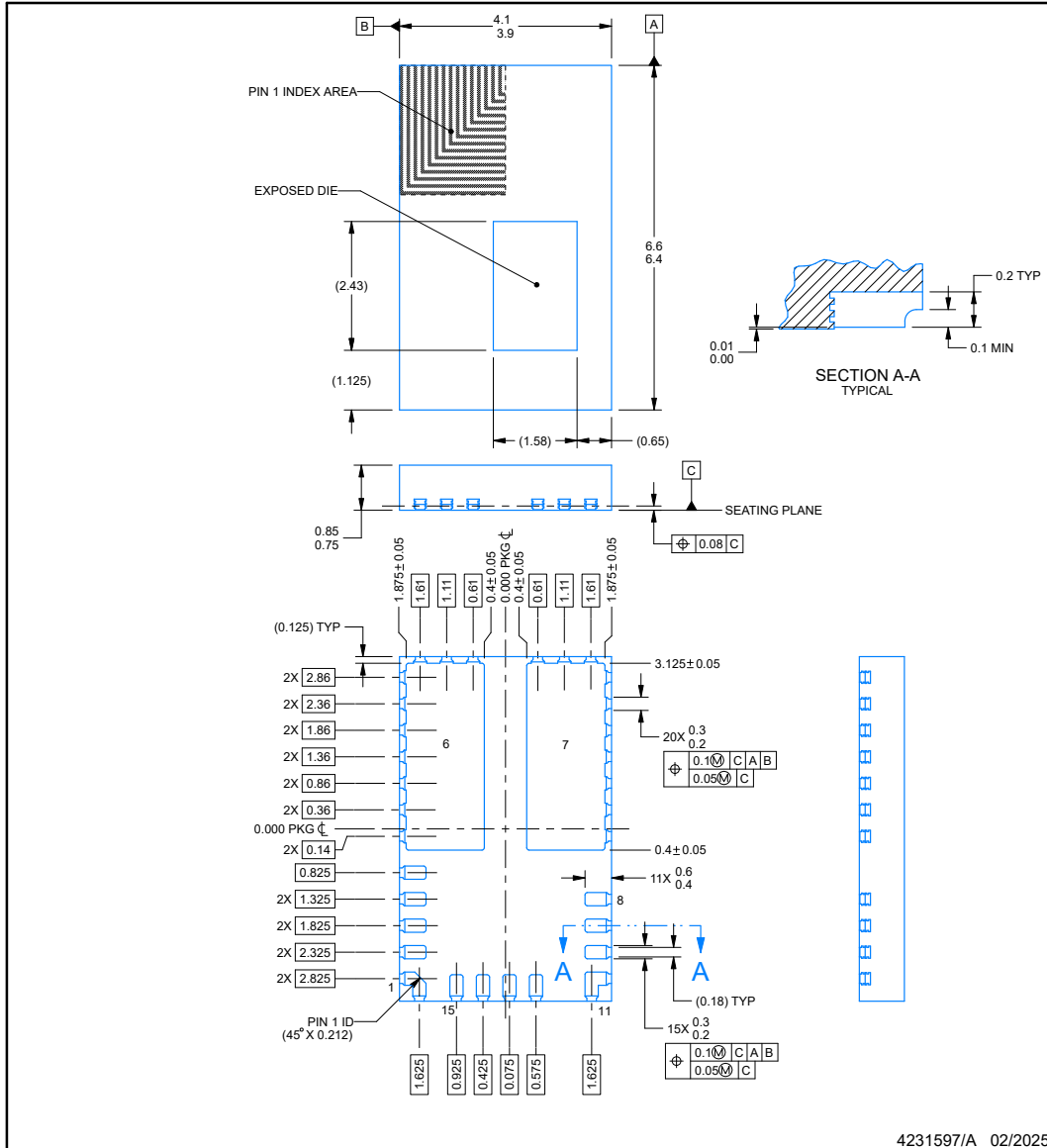


**PACKAGE OUTLINE**

**VBE0015A-C01**

**VQFN-FCRLF - 0.85 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



**NOTES:**

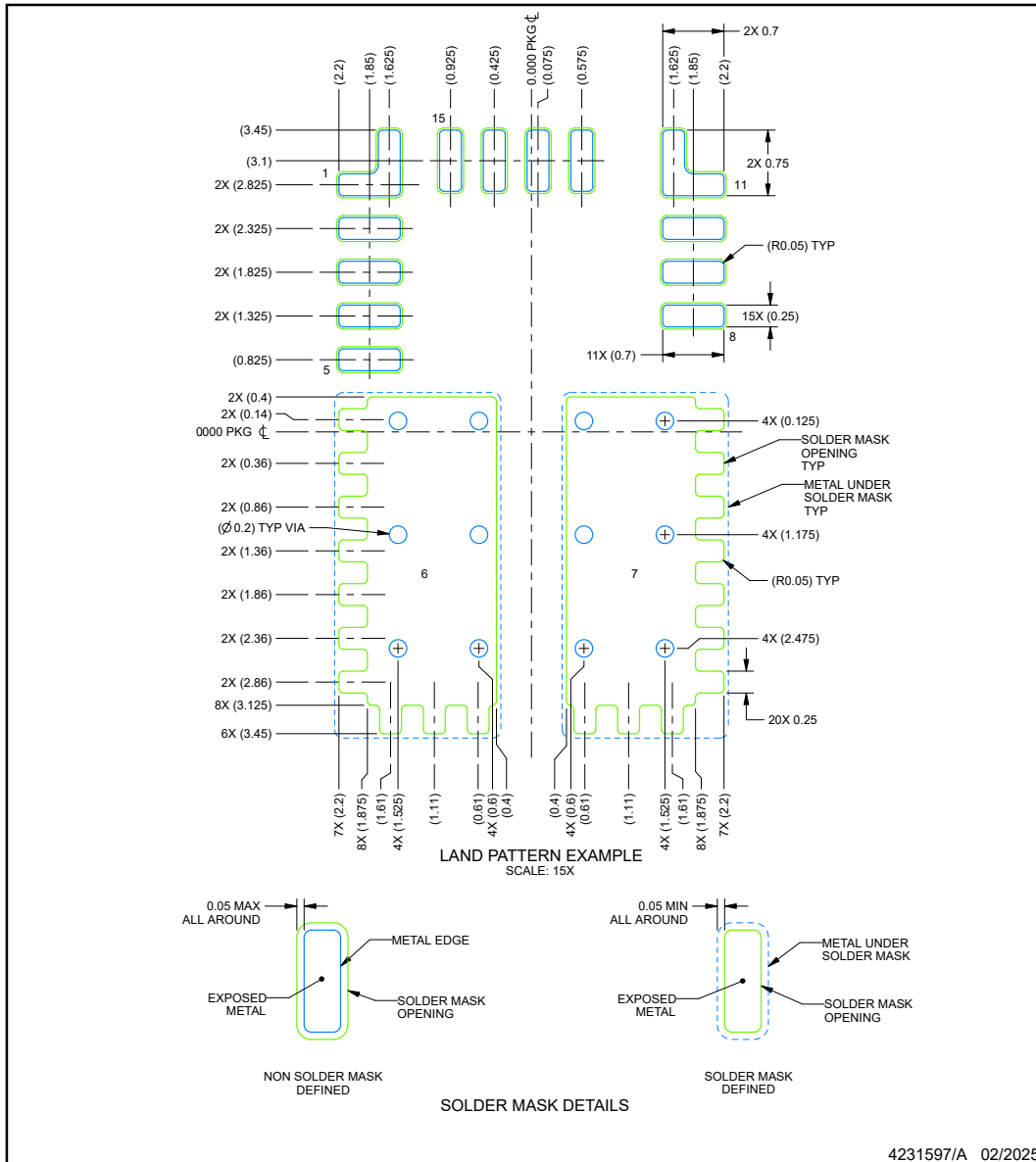
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

**EXAMPLE BOARD LAYOUT**

**VBE0015A-C01**

**VQFN-FCRLF - 0.85 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



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